• '•				
REPORT DOCUMENTATION PAGE			AFRL-SR-BL-TR-01-	
Public reporting burden for this collection of inf gathering and maintaining the data needed, an collection of information, including suggestions Davis Highway, Suite 1204, Arlington, VA 2220	d completing and reviewing the collection for reducing this burden to Washington h	of information. Send deadquarters Service:	d comr	es, he son
1. AGENCY USE ONLY (Leave blank)			AND DATE COVERED ort 01 Apr - 31 August 2001	
4. TITLE AND SUBTITLE Wavelength-Tunable, Sub-picosecond Pulsed Laser Diagnostic Tool for III-Nitride Semiconductors  6. AUTHOR(S) Stephen Teitsworth, H. Craig Casey, and Henry Everitt			5. FUNDING NUMBERS  F49620-01-1-0230	
7. PERFORMING ORGANIZATION NAME(S) AND ADDRESS(ES)  Duke University  Department of Physics  Box 90305			8. PERFORMING ORGANIZATION REPORT NUMBER	
Durham, NC 27708-0305				
<ol> <li>sponsoring/monitoring agency name(s) and address(es)         Department of the Air Force         Air Force Office of Scientific Research (AFRL)         801 North Randolph Street, Room 732         Arlington, VA 22203-1977</li> </ol>			10. SPONSORING/MONITORING AGENCY REPORT NUMBER	
11. SUPPLEMENTARY NOTES			AIR FORGE OFFICE OF SCIENTIFIC RESEARCH (AFOSR)  HAS BEEN RECEASED.	
Approved for public release			NOTICE OF TRANSMITTAL DTIC. THIS TEOGRAP & BEFORE LAW AFR 190-12. DISTRIBUTION IS UNLIMITED.	
generate wavelength tunable tools include a regenerative parametric amplifier (OPA), region from 200 nm to 15 mi which in turn drives the OF The proposal was to device characterization of the imp With the grant, a Quantronic was purchased. A Light Cor	e sub-picosecond pulses or amplifier (RA) and pure amplifier (RA) and pure amplifier (RA) and pure amplifier pre-existing the constant optoelectronic with a substant optoelectronic with a substant present the amplifier and mixed to pulse and mixed to be a substant pulse and mixed to be amplified.	in the UV-vis mp laser, a f ency mixer to g mode-locked r wavelength ide bandgap f plifier, driv arametric amp allow contin	e's capabilities, namely the ability to sible-IR spectral region. The require frequency doubled and quadrupled optico allow us to cover the entire spectrad Ti:S laser is used to pump the RA tunable, sub-picosecond optical III-N materials and heterostructures. The venbya Quantronix 527 DPH Nd:YLF laser plifier was also purchased. The TOPAS muous coverage of the spectral region sed materials.	d al l

14. SUBJECT TERMS

15. NUMBER OF PAGES
3

16. PRICE CODE

17. SECURITY CLASSIFICATION OF REPORT UNCLASSIFIED

18. SECURITY CLASSIFICATION OF THIS PAGE

UNCLASSIFIED

19. SECURITY CLASSIFICATION OF ABSTRACT

20. LIMITATION OF ABSTRACT

NSN 7540-01-280-5500 (Rev.2-89) Standard Form 298 Prescribed by ANSI Std. Z39-18 298-102

UNCLASSIFIED

## Final Report AFOSR DURIP Grant

## Wavelength-Tunable, Sub-picosecond Pulsed Laser Diagnostic Tool for III-Nitride Semiconductors

Prof. Stephen Teitsworth, Dept. of Physics, Duke Univ. Prof. H. Craig Casey, Dept. of Electrical Engineering, Duke Univ. Adj. Prof. Henry Everitt, Dept. of Physics, Duke Univ.

Duke University has an expanding research effort in III-V nitrides with three faculty (Prof. H. Craig Casey, ECE; Prof. Stephen Teitsworth, Physics; Dr. Henry Everitt, Physics & Army Research Office) currently involved in various projects. Two laboratories have been recently converted to III-N work, one focusing on electrical characterization and one focusing on optical characterization. Notable facilities include:

- a pulsed femtosecond frequency doubled and tripled Ti:Sapphire laser system,
- CW HeCd photoluminescence (PL) system,
- Xe Lamp photoluminescence excitation (PLE) system,
- high-power pulsed current-voltage (IV) system,
- radio frequency (RF) and microwave sources and detectors, and
- access to high-power tunable pulsed infrared (IR) and ultraviolet (UV) light at the Duke Free Electron Laser Laboratory (DFELL).

The requested equipment would fill a tremendous void in Duke's capabilities, namely the ability to generate wavelength tunable sub-picosecond pulses in the UV-visible-IR spectral region. The required tools include a regenerative amplifer (RA) and pump laser, a frequency doubled and quadrupled optical parametric amplifier (OPA), and a difference frequency mixer to allow us to cover the entire spectral region from 200 nm to 15 microns. The pre-existing mode-locked Ti:S laser is used to pump the RA which in turn drives the OPA as seen in Figure 1.

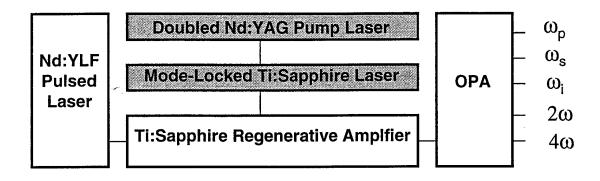


Figure 1. Diagram of requested equipment. Pre-existing equipment is shaded in gray.

We proposed to develop this capability for wavelength tunable, sub-picosecond optical characterization of the important optoelectronic wide bandgap III-N materials and heterostructures. With the AFOSR DURIP grant, we purchased a Quantronix Titan regenerative amplifier, driven by a Quantronix 527 DPH Nd:YLF laser (Figure 2). We also purchased a Light Conversion TOPAS optical parameteric amplifier. The TOPAS can be frequency doubled, quadrupled, and mixed to allow continuous coverage of the spectral region 200 nm to 15 microns, encompassing most AlGaN and all InGaN-based materials.

Originally, a Spectra Physics system was contemplated. However, Quantronix offered a superior capability (2 mJ per pulse vs. 1 mJ per pulse for Spectra Physics) and an acknolwedged superior optical parametric amplifier for a lower price. The Quantronix / Light Conversion system was purchased in the spring of 2001 and installed in the summer of 2001. We have spent the remainder of the summer reconfiguring our laboratory to accommodate the new system, including two repairs that have had to be made since installation. Once fully operational, this laser system will provide a unique capability to investigate the ultrafast, microscopic dynamics and fundamental parameters of one of the most important classes of optoelectronic materials.

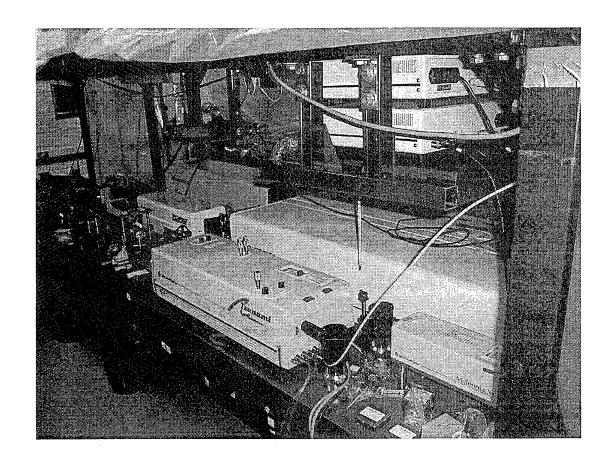


Figure 2. Installed laser system, including Quantronix Nd:YLF and Titan (background) and Light Conversion TOPAS (middle left).